
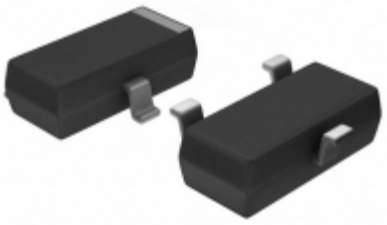
	<p>SI2316DS-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI2316DS-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 2.9A SOT23-3</p> <p>Datenblätter:  SI2316DS-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 21238 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2316DS-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 2.9A SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	21238 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	700mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.9A (Ta)
Rds On (Max) @ Id, Vgs	50 mOhm @ 3.4A, 10V
VGS (th) (Max) @ Id	800mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	7nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	215pF @ 15V
Verpackung	Tape & Reel (TR)









SI2316DS-T1-GE3 ist neu im Original, Suche SI2316DS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2316DS-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2316DS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2316DS 89K SI2316DS 89K</p>	 <p>SI2316DS-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 2.9A SOT23-3</p>	 <p>SI2318ADS-T1-GE3 V SI2318ADS-T1-GE3 V</p>	 <p>SI2316DS-T1-E3 Electro-Films (EF1) / Vishay MOSFET N-CH 30V 2.9A SOT23-3</p>
 <p>SI2317DS VISHAY SI2317DS VISHAY</p>	 <p>SI2318BDS-T1-E3 VISHAY SI2318BDS-T1-E3 VISHAY</p>	 <p>SI2317DS-T1-E3 VISHAY/PL SI2317DS-T1-E3 VISHAY/PL</p>	 <p>SI2316DS-T1-GE3 Electro-Films (EF1) / Vishay MOSFET N-CH 30V 2.9A SOT23-3</p>

heiße Teile

Mehr

 SI2314DS-T1-E3	 SI2314DS-T1-GE3	 SI2314EDS	 SI2314EDS-T1-E3	 SI2314EDS-T1-E3
 SI2314EDS-T1-GE3	 SI2314EDS-T1-GE3	 SI2315BDS	 SI2315BDS-T1-E3	 SI2315BDS-T1-E3
 SI2315BDS-T1-GE3	 SI2315BDS-T1-GE3	 SI2315DS	 SI2315DS-T1	 SI2315DS-T1-E3
 SI2315DS-T1-GE3	 SI2316-DS	 SI2316BDS-T1-E3	 SI2316BDS-T1-E3	 SI2316BDS-T1-GE3
 SI2316BDS-T1-GE3	 SI2316DS	 SI2316DS-T1-E3	 SI2316DS-T1-E3	 SI2316DS-T1-GE3
 SI2317DS	 SI2317DS-T1-E3	 SI2318ADS-T1-GE3	 SI2318BDS-T1-E3	 SI2318BDS-T1-GE3
 SI2318CDS-T1-E3	 SI2318CDS-T1-GE3	 SI2318CDS-T1-GE3	 SI2318DS	 SI2318DS-T1-E3
 SI2318DS-T1-E3	 SI2318DS-T1-GE3	 SI2318DS-T1-GE3	 SI2319ADS-T1-GE3	 SI2319C95TF
 SI2319CDS-T1-E3	 SI2319CDS-T1-GE3	 SI2319CDS-T1-GE3	 SI2319DDS-T1-GE3	 SI2319DS
 SI2319DS-T1-E3	 SI2319DS-T1-E3	 SI2319DS-T1-GE3	 SI2319DS-T1-GE3	 SI2320DS

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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